



AAT7211

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ONE CHANNEL RAIL-TO-RAIL OPERATIONAL AMPLIFIER

FEATURES

- 4.5V to 20V Input Voltage Range
- Rail-to-Rail Output Swing
- Maximum Peak Output Current : 1300mA
- Slew Rate : 40V/μS
- Supply Current : 3.0mA
- 30MHz Bandwidth
- Protections
  - ◆ Over Current Protection (OCP)
  - ◆ Short Circuit Protection (SCP)
  - ◆ Thermal Shutdown (OTP)
- Package Available
  - ◆ TSOT 23-5 Package
  - ◆ WSON8 3x3x0.75 Package
  - ◆ MSOP8 (Power Pad) Package

GENERAL DESCRIPTION

The AAT7211 is a device that includes one channel rail-to-rail operational amplifier, designed for use as a buffer in thin film transistor liquid crystal display (TFT LCD). This device has an input voltage range from 4.5V to 20V, exhibits low supply current of 3.0mA. It has rail to rail output swing capability, a slew rate of typically 40V/μs, and a maximum output current capability of 1300mA. A 30MHz open loop -3dB bandwidth allows for fast transient response and fast settling time.

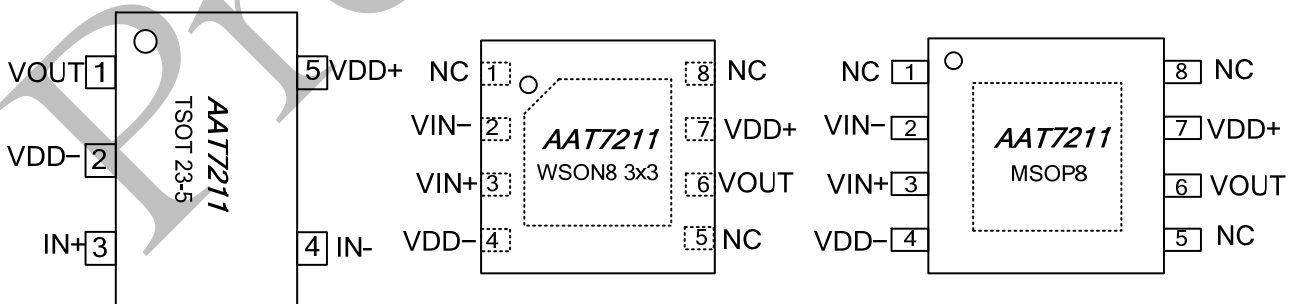
The AAT7211 includes various protection features such as over current protection (OCP), short circuit protection (SCP) and Thermal Shutdown (OTP).

The AAT7211 is available in a TSOT 23-5, a small 3x3x0.75mm, ultra-thin WSON8 package, and 8 pin MSOP8 (Power Pad) package. WSON8 & MSOP8 (Power Pad) packages have a bottom side exposed thermal pad to provide optimal heat dissipation. The packages offered for the AAT7211 make it an ideal component for use in space-sensitive designs of LCD panel. The device is rated to operate from -40°C to +85°C ambient temperature range.

APPLICATIONS

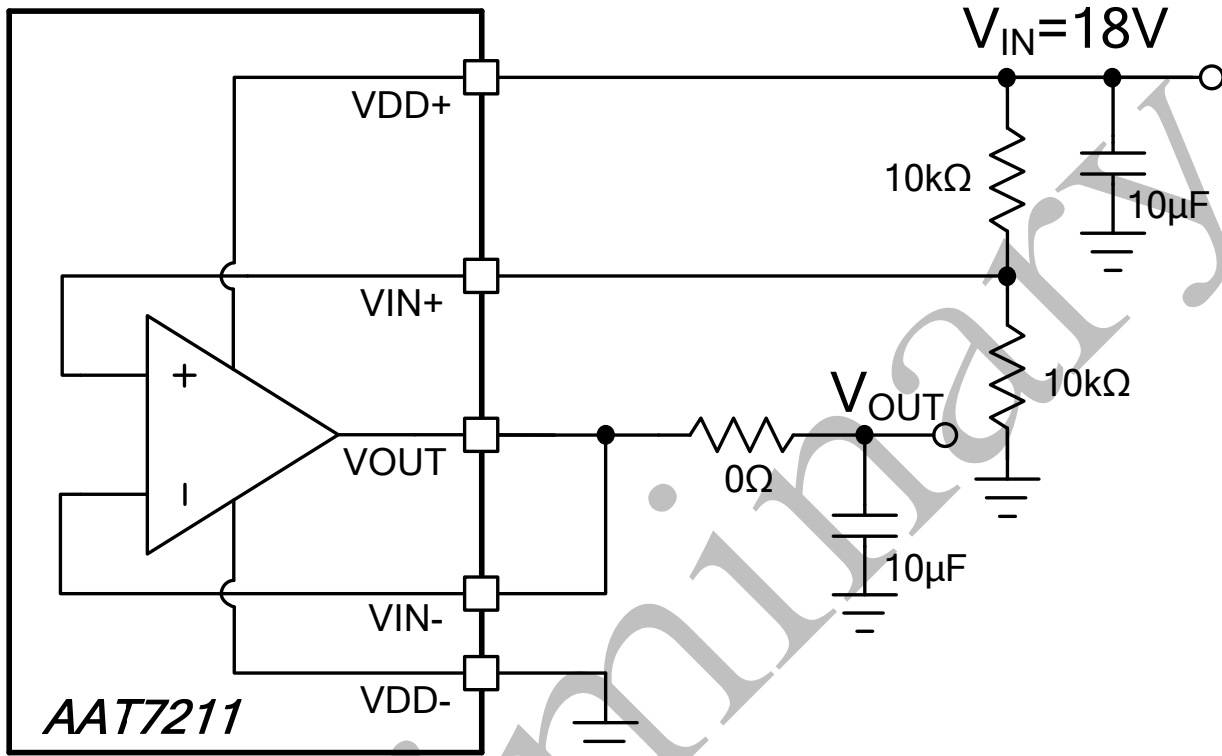
- TFT LCD Panel

PIN CONFIGURATION





## TYPICAL APPLICATION



## ORDERING INFORMATION

DEVICE TYPE	PART NUMBER	PACKAGE	PACKING	TEMP. RANGE	MARKING	MARKING DESCRIPTION
AAT7211	AAT7211-S18-T	S18:TSOT 23-5	T: Tape and Reel	-40 °C to +85 °C	E02YY	E02=AAT7211, YY= tracing code, AA, AB, AC...
AAT7211	AAT7211-Q42-T	Q42:WSON8	T: Tape and Reel	-40 °C to +85 °C	AAT7211 XXXXXX	Device Type Lot no. (6~9 Digits)
AAT7211	AAT7211-M3-T	M3 : MSOP8 (Power Pad)	T: Tape and Reel	-40 °C to +85 °C	AAT7211 XXXXXX	Device Type Lot no. (6~9 Digits)

Note: All AAT products are lead free and halogen free.



## ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
VDD+ to GND	$V_{IN}$	-0.3 to +22.0	V
VDD+ to VDD-	$V_{IN\_G}$	20	V
Input Voltage (VIN+, VIN-)	$V_{IN+}, V_{IN-}$	-0.3 to ( $V_{IN} + 0.3$ )	V
Output Voltage (VOUT)	$V_{OUT}$	-0.3 to ( $V_{IN} + 0.3$ )	V
Maximum Peak Output Current	$I_{PEAK\_MAX}$	1,500	mA
Operating Ambient Temperature Range	$T_A$	-40 to +85	°C
Operating Junction Temperature Range	$T_J$	-40 to +150	°C
Storage Temperature Range	$T_{STORAGE}$	-65 to +150	°C
Package Thermal Resistance – TSOT 23-5	$\theta_{JA}$	275	°C/W
Power Dissipation, @ $T_A = +25^\circ\text{C}$ , $T_J = +125^\circ\text{C}$ – TSOT 23-5	$P_d$	0.364	W
Package Thermal Resistance – WSON8	$\theta_{JA}$	47	°C/W
Power Dissipation, @ $T_A = +25^\circ\text{C}$ , $T_J = +125^\circ\text{C}$ – WSON8	$P_d$	2.128	W
Package Thermal Resistance – MSOP8 (Power Pad)	$\theta_{JA}$	128.3	°C/W
Power Dissipation, @ $T_A = +25^\circ\text{C}$ , $T_J = +125^\circ\text{C}$ – MSOP8	$P_d$	0.779	W
ESD Susceptibility Human Body Mode		2K	V
ESD Susceptibility Machine Mode		200	V

Note: Stresses above those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the devices. Exposure to ABSOLUTE MAXIMUM RATINGS conditions for extended periods may affect device reliability.

## RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	MIN	MAX	UNIT
Operating Ambient Temperature	$T_A$	-40	+85	°C
Power Supply Voltage (VIN)	$V_{IN}$	4.5	20.0	V



## ELECTRICAL CHARACTERISTICS

(VDD+ = 18V, VDD- = 0V, V<sub>IN+</sub> = V<sub>OUT</sub> = (VDD+)/2, R<sub>L</sub> = 0Ω and C<sub>L</sub> = 10μF, Typical values are tested at +25°C ambient temperature.)

### Operational Amplifier

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Supply Voltage Range	V <sub>IN</sub>		4.5	-	20.0	V
Supply Current	I <sub>QS</sub>	No Load	-	3.0	-	mA
Input Offset Voltage	V <sub>OS</sub>	V <sub>IN+</sub> = 9V	-15	±2	+15	mV
Input Bias Current	I <sub>B</sub>	V <sub>IN+</sub> = 9V	-40	-	+40	nA
Output Swing Low	V <sub>OL</sub>	V <sub>IN+</sub> = 0V, I <sub>L</sub> = -5mA	-	50	150	mV
Output Swing High	V <sub>OH</sub>	V <sub>IN+</sub> = 18V, I <sub>L</sub> = +5mA	17.85	17.95	-	V
Continuous Output Current	I <sub>O</sub>	V <sub>DD+</sub> = 16V, V <sub>IN+</sub> = 8V	±300	±350	-	mA
Transient Peak Output Current	I <sub>O_PEAK</sub>		±1,100	±1,300	-	mA
Slew Rate	SR	+0.5V < V <sub>OUT</sub> < 17.5V; 20% to 80%	25	40	-	V/μS
Setting Time	t <sub>s</sub>		-	200	-	nS
Bandwidth	BW	-3dB	-	30	-	MHz
Voltage Gain	A <sub>V</sub>	R <sub>L</sub> = 10kΩ, C <sub>L</sub> = 50pF	0.99	-	1.01	V/V
Open-Loop Gain	A <sub>VOL</sub>		60	70	-	dB
Power Supply Rejection Ratio	PSRR	+6V < VDD+ < +18V	54	80	-	dB
Common-Mode Input Range	CMIR		-0.5	-	+17.5	V
Common-Mode Rejection Ratio	CMRR		50	70	-	dB
Over Current Protection	I <sub>OCP</sub>	V <sub>DD+</sub> = 16V, V <sub>IN+</sub> = 8V	-	550	-	mA
Thermal Shutdown	T <sub>SD</sub>		-	150	-	°C



## PIN DESCRIPTION

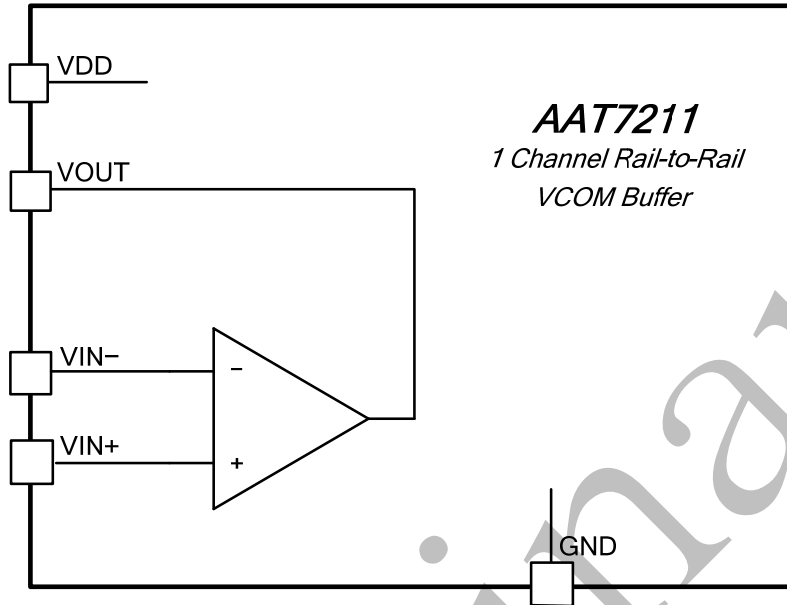
PIN	NAME	I/O	FUNCTION
TSOT23-5			
1	VOUT	O	Output of the Amplifier
2	VDD-	-	Negative Power Supply
3	VIN+	I	Non-Inverted input Pin of the Amplifier
4	VIN-	I	Inverted Input Pin of the Amplifier
5	VDD+	I	Positive Power Supply

PIN	NAME	I/O	FUNCTION
WSO8			
1	NC	-	No Connected
2	VIN-	I	Inverted Input Pin of the Amplifier
3	VIN+	I	Non-Inverted Input Pin of the Amplifier
4	VDD-	-	Negative Power Supply
5	NC	-	No Connected
6	VOUT	O	Output of the Amplifier
7	VDD+	I	Positive Power Supply
8	NC	-	No Connected

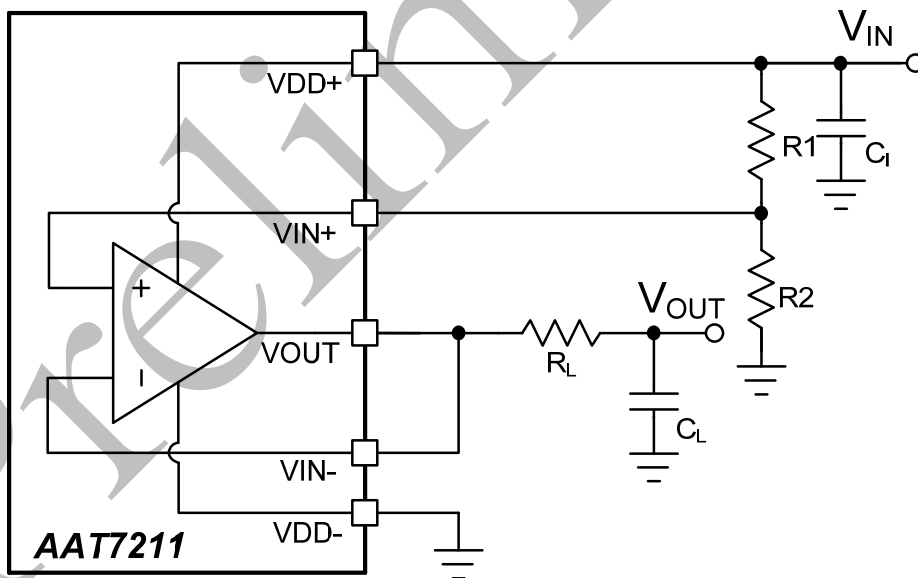
PIN	NAME	I/O	FUNCTION
MSOP8			
1	NC	-	No Connected
2	VIN-	I	Inverted Input Pin of the Amplifier
3	VIN+	I	Non-Inverted Input Pin of the Amplifier
4	VDD-	-	Negative Power Supply
5	NC	-	No Connected
6	VOUT	O	Output of the Amplifier
7	VDD+	I	Positive Power Supply
8	NC	-	No Connected



## FUNCTION BLOCK DIAGRAM



## TYPICAL APPLICATION CIRCUIT

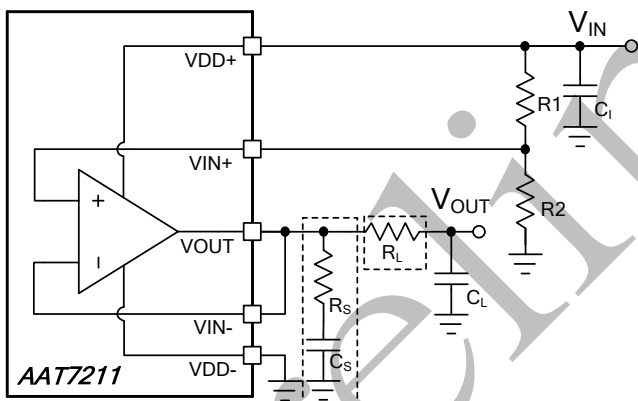




## APPLICATION NOTE

The operational amplifier drives the LCD backplane VCOM divider string. The Op Amp is capable of rail-to-rail input and output,  $\pm 1,300\text{mA}$  maximum peak output current, and a  $40\text{V}/\mu\text{s}$  slew rate. In typical application, the inverting input is shorted to the output for a unity-gain (voltage follower) configuration.

In the unity-gain configuration, the capacitive load adds a pole to the loop gain that impacts the stability of the system and leads to output peaking, ringing and oscillation. A higher pole frequency results in greater stability. In fact, if the pole frequency is lower than or close to the unity gain frequency, the pole can have a significant negative impact on phase and gain margins. Therefore, the stability decreases when the capacitive load increases. One method of improving capacitive load drive is to insert a  $2\Omega$  to  $20\Omega$  resistor ( $R_L$ ) in series with the output, as shown in Figure 1.



**Figure 1. Operational Amplifier Functional Block Diagram**

This reduces ringing with large capacitive loads while maintaining DC accuracy. However, for typical applications, the AAT7211 should be able to handle the capacitive load with sufficient phase margin. Thus, adding the resistor  $R_L$  is usually not critical.

Another method for improving transient response is to add a snubber circuit at the output. A snubber circuit

consists of a resistor ( $R_S$ ) in series with a capacitor ( $C_S$ ), which improves output settling time and reduces peaking. The advantage of this topology is that it draws no DC current nor does it reduce the gain.

### Bypass Capacitors

For stability while driving load transients, and to minimize the noise to the system, use a  $10\mu\text{F}$  capacitor for the VDD Pin supply. Connect this bypass capacitor as close as possible to the input VDD+.

### Protection

When one of the three protection mechanism (OCP, SCP, OTP) is triggered, shutdown mode will be latched. For the device to resume operation when nominal conditions have returned, the power VDD+ must be recycled to restart.

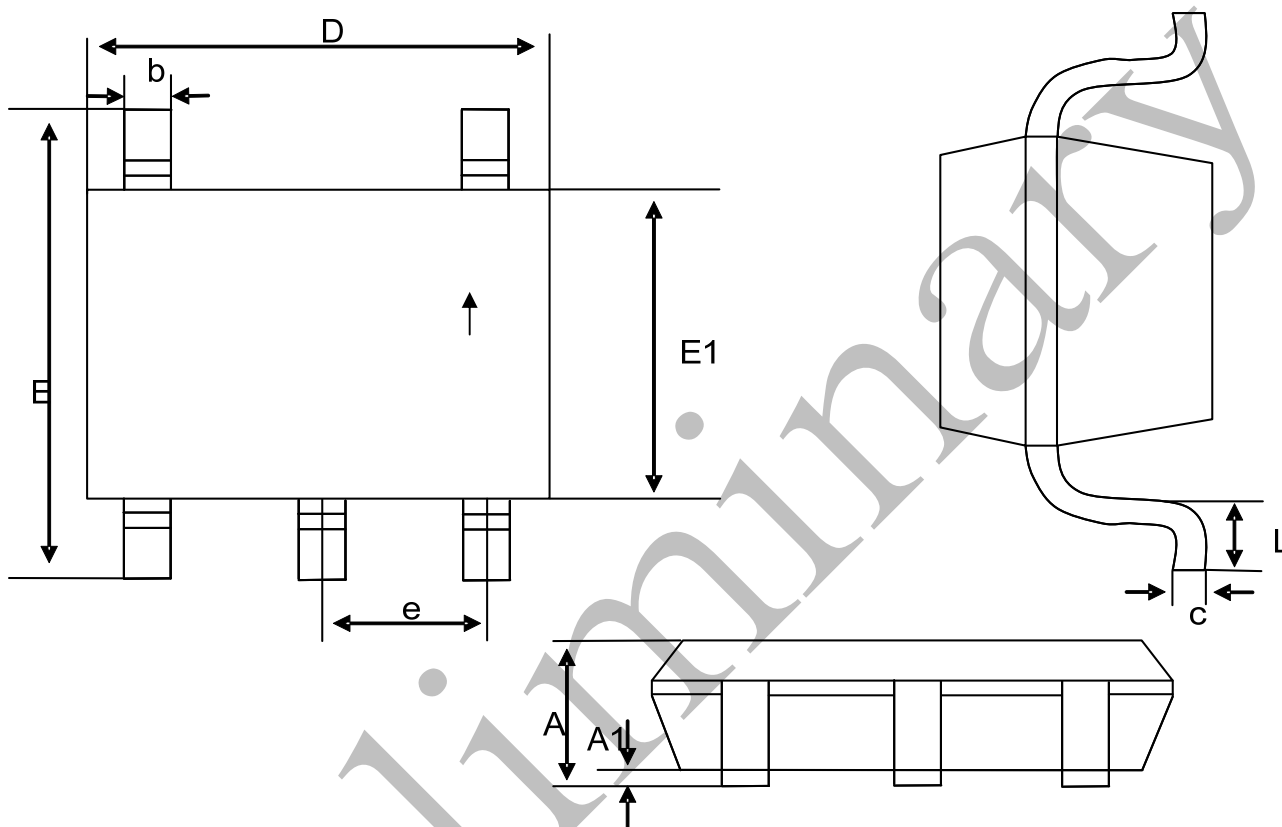
### Layout

Connect the exposed pad of the device to the VDD- or GND plane for best thermal dissipation performance, or low thermal resistance. In typical application, VDD- is connected to ground.



## PACKAGE DIMENSION

### TSOT23-5 (TSOT25)



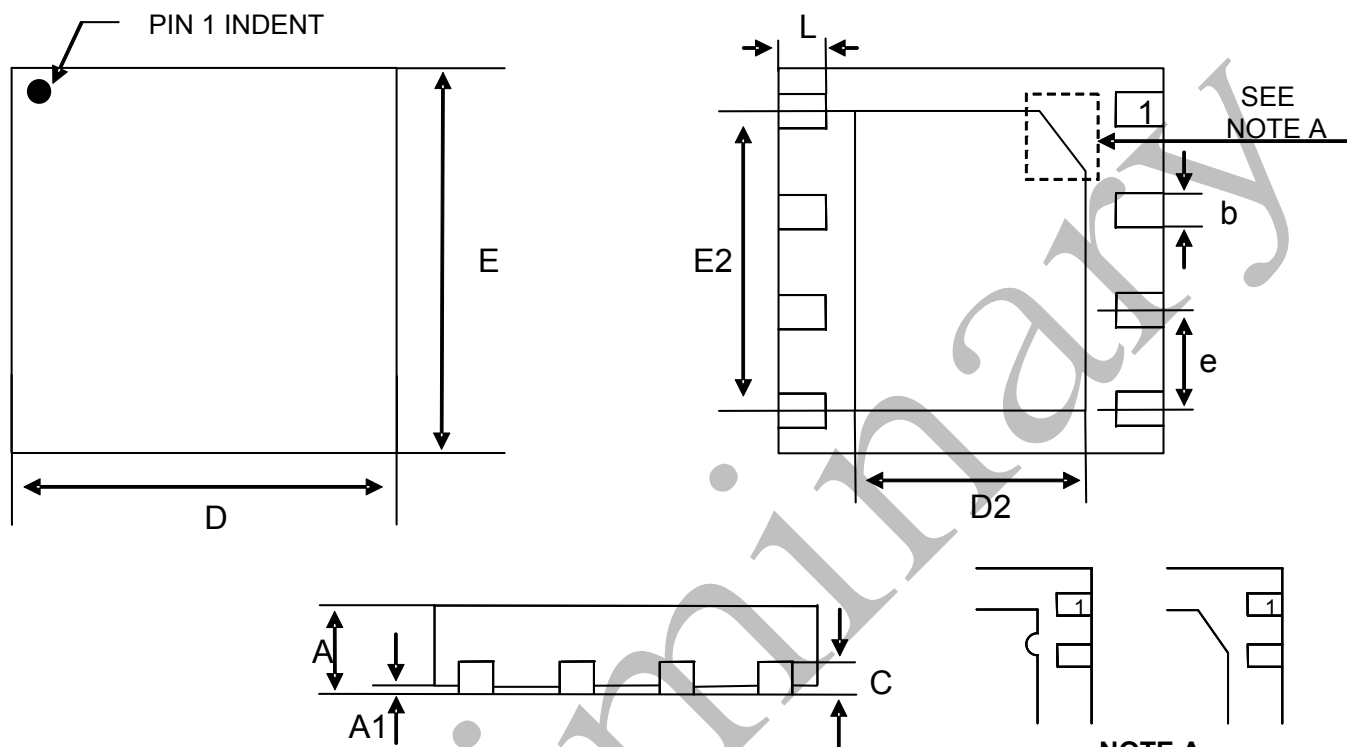
Symbol	Dimensions In Millimeters		
	MIN	TYP	MAX
A	0.70	-----	1.00
A1	0.05	-----	0.10
b	0.30	-----	0.50
c	0.08	-----	0.20
D	2.70	2.90	3.10
E	2.60	2.80	3.00
E1	1.40	1.60	1.80
e	0.85	0.95	1.05
L	0.30	0.45	0.60





## PACKAGE DIMENSION

### WSO8-3X3



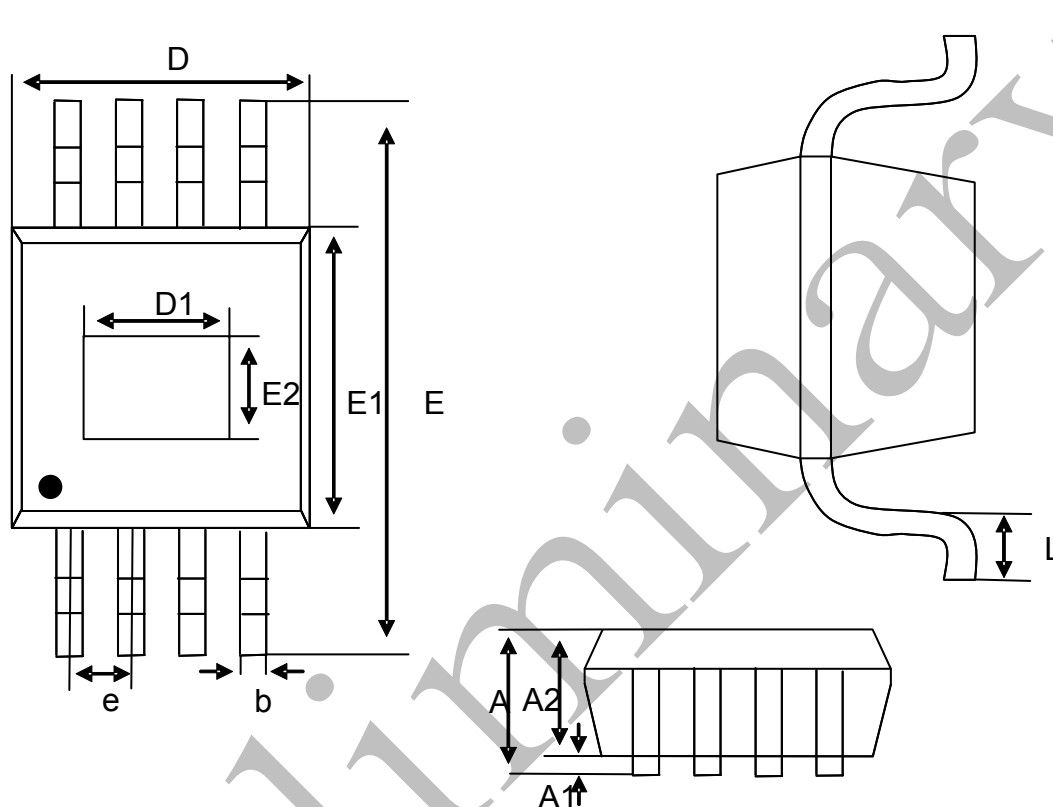
The tie bar mark of Pin#1 is optional as the above configuration

Symbol	Dimensions In Millimeters		
	MIN	TYP	MAX
A	0.7	0.75	0.8
A1	0	0.02	0.05
b	0.2	0.25	0.3
C	-----	0.2	-----
D	2.95	3	3.05
D2	1.45	1.5	1.55
E	2.95	3	3.05
E2	2.25	2.3	2.35
e	-----	0.65	-----
L	0.425	0.475	0.525



# PACKAGE DIMENSION

## MSOP8 Exposed Pad



Symbol	Dimensions In Millimeters		
	MIN	TYP	MAX
A	----	----	1.1000
A1	0.0500	----	0.1500
A2	0.7600	0.8500	0.9500
b	0.2500	0.3000	0.3500
D	2.9000	3.0000	3.1000
D1	----	1.2800	----
E	4.8000	4.9000	5.0000
E1	2.9000	3.0000	3.1000
E2	----	1.2192	----
e	----	0.6500	----
L	0.4000	0.5300	0.6600